UNISONIC TECHNOLOGIES CO., LTD

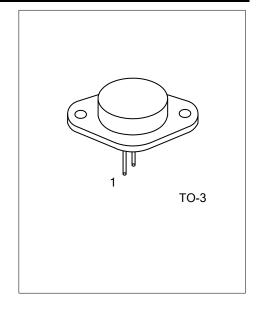
2N3772

SILICON NPN TRANSISTOR

SILICON NPN TRANSISTORS

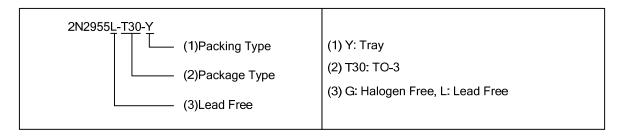
DESCRIPTION

The UTC 2N3772 is a silicon power transistor in TO-3 metal case. It is designed for linear amplifiers, series pass regulators, and inductive switching applications.



ORDERING INFORMATION

Ordering Number		Daalaasa	Pin Assignment			Daakina	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2N3772L-T30-Y	2N3772G-T30-Y	TO-3	В	Е	С	Tray	



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■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector-Emitter Voltage	V_{CEV}	80	V
Collector Current	Ic	30	Α
Collector Peak Current (Note 1)	Ісм	30	Α
Base Current	I _B	5	Α
Base Peak Current (Note 1)	I _{BM}	15	Α
Power Dissipation (T _A =25°ℂ)	P _D	150	W
Junction Temperature	T_J	150	$^{\circ}$
Storage Temperature	T _{STG}	-55 ~ +150	$^{\circ}\!\mathbb{C}$

Note 1. Pulse Test: P_W <=300 μ s, Duty Cycle<=2%

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Collector-Emitter Sustaining Voltage	V _{CEX(SUS)}	$I_{C}=0.2A, V_{BE(OFF)}=1.5V, R_{BE}=100\Omega$	80			V		
Collector-Emitter Sustaining Voltage	V _{CER(SUS)}	$I_C=0.2A, R_{BE}=100\Omega$	70			V		
Collector-Emitter Sustaining Voltage	V _{CEO(SUS)}	I _C =0.2A, I _B =0	60			V		
Collector Cut-off Current	I _{CEO}	V_{CE} =50 V , I_{B} =0			10	mA		
Collector Cut-off Current		V _{CE} =100V, V _{BE(OFF)} =1.5V.			5	mA		
Collector Cut-on Current	I _{CEX}	V _{CE} =30V, V _{BE(OFF)} =1.5V, T _A =150°C			10			
Collector Cut-off Current	I _{CBO}	V_{CE} =50 V , I_{E} =0			5	mA		
Emitter Cut-off Current	I _{EBO}	V_{BE} =7V, I_{C} =0			5	mA		
ON CHARACTERISTICS								
DC Current Cain (Note)	l h	I _C =10A,V _{CE} =4V	15		60			
DC Current Gain (Note)		I _C =20A, V _{CE} =4V	5					
Callagter Freitter Caturation Valtage		I _C =10A, I _B =1.5A			1.4	_		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =20A, I _B =4A			4.0			
Base-Emitter On Voltage	V _{BE(ON)}	I _C =10A, V _{CE} =4V			2.2	V		
SECOND BREAKDOWN								
Second Breakdown Collector with Base	I _S /b	V =60V T=1 00 Non repetitive	2.5			Α		
Forward Biased		V _{CE} =60V, T=1.0s, Non-repetitive				Α		
DYNAMIC CHARACTERISTICS								
Current Gain-Bandwidth Product	f _T	I _C =1A, V _{CE} =4V, f=50kHz	0.2			MHz		
Small-Signal Current Gain	h _{FE}	I _C =1A, V _{CE} =4V, f=1kHz	40					

Note: Pulse Test: $P_W \!\! < \!\! = \!\! 300 \mu s,$ Duty Cycle $\!\! < \!\! = \!\! 2\%$

^{2.} Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

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